



Precision, 8-Channel/Dual 4-Channel, Low-Voltage, CMOS Analog Multiplexers

MAX398/MAX399

General Description

The MAX398/MAX399 precision, monolithic, CMOS analog multiplexers (muxes) offer low on-resistance (less than 100Ω), which is matched to within 6Ω between channels and remains flat over the specified analog signal range (11Ω max). They also offer low leakage over temperature (NO-off leakage current less than 2.5nA at +85°C) and fast switching speeds (transition time less than 250ns). The MAX398 is an 8-channel device, and the MAX399 is a dual 4-channel device.

The MAX398/MAX399 are fabricated with Maxim's low-voltage silicon-gate process. Design improvements yield extremely low charge injection (less than 5pC) and guarantee electrostatic discharge protection (ESD) greater than 2000V.

These muxes operate with a single +3V to +15V supply or bipolar ±3V to ±8V supplies, while retaining CMOS-logic input compatibility and fast switching. CMOS inputs provide reduced input loading. The MAX398/MAX399 are pin compatible with the industry-standard DG408, DG409, DG508A, and DG509A.

Applications

- Sample-and-Hold Circuits
- Automatic Test Equipment
- Heads-Up Displays
- Guidance and Control Systems
- Military Radios
- Communications Systems
- Battery-Operated Systems
- PBX, PABX
- Audio Signal Routing
- Low-Voltage Data Acquisition Systems

Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

Features

- ◆ Pin Compatible with Industry-Standard DG408/DG409/DG508A/DG509A
- ◆ Guaranteed On-Resistance Match Between Channels (<6Ω)
- ◆ Low On-Resistance (<100Ω)
- ◆ Guaranteed Flat On-Resistance over Signal Range (<11Ω)
- ◆ Guaranteed Low Charge Injection (<5pC)
- ◆ NO-Off Leakage Current <1nA at +85°C
- ◆ COM-Off Leakage Current <2.5nA at +85°C
- ◆ ESD Protection >2000V
- ◆ +3V to +15V Single-Supply Operation
±3V to ±8V Bipolar-Supply Operation
- ◆ Low Power Consumption (<300μW)
- ◆ Rail-to-Rail® Signal Handling
- ◆ TTL/CMOS-Logic Compatible

Ordering Information

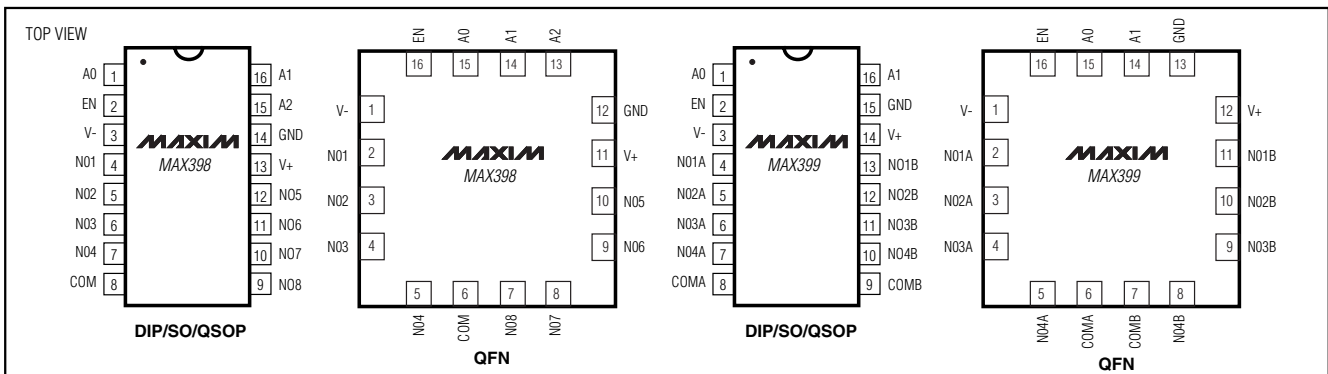
PART	TEMP. RANGE	PIN-PACKAGE
MAX398CGE	0°C to +70°C	16 QFN
MAX398CEE	0°C to +70°C	16 QSOP
MAX398CSE	0°C to +70°C	16 Narrow SO
MAX398CPE	0°C to +70°C	16 Plastic DIP
MAX398C/D	0°C to +70°C	Dice*
MAX398EGE	-40°C to +85°C	16 QFN
MAX398EEE	-40°C to +85°C	16 QSOP
MAX398ESE	-40°C to +85°C	16 Narrow SO
MAX398EPE	-40°C to +85°C	16 Plastic DIP
MAX398EJE	-40°C to +85°C	16 CERDIP**
MAX398MJE	-55°C to +125°C	16 CERDIP**

Ordering Information continued at end of data sheet.

* Contact factory for dice specifications.

** Contact factory for package availability.

Pin Configurations



For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

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ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to GND

V+-0.3V to +17V
 V-+0.3V to -17V
 V+ to V-.....-0.3V to +17V

Voltage into Any Terminal (Note 1).....(V- - 2V) to (V+ + 2V) or 30mA (whichever occurs first)

Current into Any Terminal30mA

Peak Current, Any Terminal (pulsed at 1ms, 10% duty cycle max)40mA

Continuous Power Dissipation (T_A = +70°C)

QFN (derate 18.5mW/°C above +70°C)1484mW
 QSOP (derate 8.3mW/°C above +70°C)667mW
 Narrow SO (derate 8.7mW/°C above +70°C)696mW
 Plastic DIP (derate 7.5mW/°C above +70°C).....470mW
 CERDIP (derate 10.0mW/°C above +70°C).....900mW

Operating Temperature Ranges

MAX39_C_0°C to +70°C
 MAX39_E_-40°C to +85°C
 MAX39_MJE-55°C to +125°C
 Storage Temperature Range-65°C to +150°C
 Lead Temperature (soldering, 10s)+300°C

Note 1: Signals on any terminal exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current ratings.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = +5V ±10%, V- = -5V ±10%, GND = 0, V_{AH} = V_{ENH} = +2.4V, V_{AL} = V_{ENL} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS	
SWITCH								
Analog Signal Range	V _{COM} , V _{NO}	(Note 3)		V-		V+	V	
Channel On-Resistance	R _{ON}	I _{NO} = 1mA, V _{COM} = ±3.5V	T _A = +25°C	60	100		Ω	
			T _A = T _{MIN} to T _{MAX}		125			
R _{ON} Matching Between Channels (Note 4)	ΔR _{ON}	I _{NO} = 1mA, V _{COM} = ±3.5V, V+ = 5V, V- = -5V	T _A = +25°C		6		Ω	
			T _A = T _{MIN} to T _{MAX}		8			
On-Resistance Flatness (Note 5)	R _{FLAT(ON)}	I _{NO} = 1mA, V _{COM} = ±3V, V+ = 5V, V- = -5V	T _A = +25°C		11		Ω	
			T _A = T _{MIN} to T _{MAX}		14			
NO-Off Leakage Current (Note 6)	I _{NO(OFF)}	V _{NO} = ±4.5V, V _{COM} = ±4.5V, V+ = 5.5V, V- = -5.5V	T _A = +25°C	-0.1	0.1		nA	
			T _A = T _{MIN} to T _{MAX}	C, E	-1.0			1.0
				M	-10			10
COM-Off Leakage Current (Note 6)	I _{COM(OFF)}	V _{COM} = ±4.5V, V _{NO} = ±4.5V, V+ = 5.5V, V- = -5.5V	MAX398	T _A = +25°C	-0.2	0.2	nA	
				T _A = T _{MIN} to T _{MAX}	C, E	-2.5		2.5
					M	-20		20
		V _{COM} = ±4.5V, V _{NO} = ±4.5V, V+ = 5.5V, V- = -5.5V	MAX399	T _A = +25°C	-0.1	0.1		
				T _A = T _{MIN} to T _{MAX}	C, E	-1.5		1.5
					M	-10		10
COM-On Leakage Current (Note 6)	I _{COM(ON)}	V _{COM} = ±4.5V, V _{NO} = ±4.5V	MAX398	T _A = +25°C	-0.4	0.4	nA	
				T _A = T _{MIN} to T _{MAX}	C, E	-5		5
					M	-40		40
		V _{COM} = ±4.5V, V _{NO} = ±4.5V	MAX399	T _A = +25°C	-0.2	0.2		
				T _A = T _{MIN} to T _{MAX}	C, E	-2.5		2.5
					M	-20		20

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ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V+ = +5V ±10%, V- = -5V ±10%, GND = 0, V_{AH} = V_{ENH} = +2.4V, V_{AL} = V_{ENL} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
DIGITAL LOGIC INPUT							
Logic High Input Voltage	V _{AH} , V _{ENH}		T _A = T _{MIN} to T _{MAX}	2.4			V
Logic Low Input Voltage	V _{AL} , V _{ENL}		T _A = T _{MIN} to T _{MAX}			0.8	V
Input Current with Input Voltage High	I _{AH} , I _{ENH}	V _A = V _{EN} = 2.4V		-0.1		0.1	μA
Input Current with Input Voltage Low	I _{AL} , I _{ENL}	V _A = V _{EN} = 0.8V		-0.1		0.1	μA
SUPPLY							
Power-Supply Range				±3		±8	V
Positive Supply Current	I ₊	V _{EN} = V _A = 0V/V+, V ₊ = 5.5V, V ₋ = -5.5V	T _A = +25°C	-1		1	μA
Negative Supply Current	I ₋	V _{EN} = V _A = 0V/V+, V ₊ = 5.5V, V ₋ = -5.5V	T _A = T _{MIN} to T _{MAX}	-1		1	μA
Ground Current	I _{GND}	V _{EN} = V _A = 0V/V+, V ₊ = 5.5V, V ₋ = -5.5V	T _A = +25°C	-1		1	μA
			T _A = T _{MIN} to T _{MAX}	-1		1	
DYNAMIC							
Transition Time	t _{TRANS}	Figure 2				150	ns
Break-Before-Make Interval	t _{OPEN}	Figure 4	T _A = +25°C	0	40		ns
Enable Turn-On Time	t _{ON(EN)}	Figure 3	T _A = +25°C		60	150	ns
			T _A = T _{MIN} to T _{MAX}			250	
Enable Turn-Off Time	t _{OFF(EN)}	Figure 3	T _A = +25°C		40	150	ns
			T _A = T _{MIN} to T _{MAX}			200	
Charge Injection (Note 3)	Q	C _L = 10nF, V _S = 0, R _S = 0Ω	T _A = +25°C		2	5	pC
Off-Isolation (Note 7)		V _{EN} = 0, R _L = 1kΩ, f = 100kHz	T _A = +25°C		-75		dB
Crosstalk Between Channels	V _{CT}	V _{EN} = 2.4V, f = 100kHz, V _{GEN} = 1V _{p-p} , R _L = 1kΩ	T _A = +25°C		-92		dB
Logic Input Capacitance	C _{IN}	f = 1MHz	T _A = +25°C		8		pF
NO-Off Capacitance	C _{NO(OFF)}	f = 1MHz, V _{EN} = V _D = 0V	T _A = +25°C		11		pF
COM-Off Capacitance	C _{COM(OFF)}	f = 1MHz, V _{EN} = V _D = 0V	MAX398	T _A = +25°C	40		pF
			MAX399		20		
COM-On Capacitance	C _{COM(ON)}	f = 1MHz, V _{EN} = V _D = 0V	MAX398	T _A = +25°C	54		pF
			MAX399		34		

MAX398/MAX399

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ELECTRICAL CHARACTERISTICS—Single +5V

(V+ = 5V ±10%, V- = 0, GND = 0, VAH = VENH = +2.4V, VAL = VENL = +0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS	
SWITCH								
Analog Signal Range	VCOM, VNO	(Note 3)		V-		V+	V	
On-Resistance	RON	INO = 1mA, VCOM = 3.5V, V+ = 4.5V		TA = +25°C	150	225	Ω	
				TA = TMIN to TMAX		280		
RON Matching Between Channels (Note 4)	ΔRON	INO = 1mA, VCOM = 3.5V, V+ = 4.5V		TA = +25°C		11	Ω	
				TA = TMIN to TMAX		13		
On-Resistance Flatness	RFLAT	INO = 1mA; VCOM = 3V, 2V, 1V; V+ = 5V		TA = +25°C	10	18	Ω	
				TA = TMIN to TMAX	15	22		
NO-Off Leakage Current (Note 8)	INO(OFF)	VNO = 4.5V, VCOM = 0, V+ = 5.5V		TA = +25°C	-0.1	0.1	nA	
				TA = TMIN to TMAX	C, E	-1.0		1.0
					M	-10		10
COM-Off Leakage Current (Note 8)	ICOM(OFF)	VCOM = 4.5V, VNO = 0, V+ = 5.5V	MAX398	TA = +25°C	-0.2	0.2	nA	
				TA = TMIN to TMAX	C, E	-2.5		2.5
					M	-20		20
		VCOM = 4.5V, VNO = 0, V+ = 5.5V	MAX399	TA = +25°C	-0.1	0.1		
				TA = TMIN to TMAX	C, E	-1.5		1.5
					M	-10		10
COM-On Leakage Current (Note 8)	ICOM(ON)	VCOM = 4.5V, VNO = 4.5V, V+ = 5.5V	MAX398	TA = +25°C	-0.4	0.4	nA	
				TA = TMIN to TMAX	C, E	-5		5
					M	-40		40
		VCOM = 4.5V, VNO = 4.5V, V+ = 5.5V	MAX399	TA = +25°C	-0.2	0.2		
				TA = TMIN to TMAX	C, E	-2.5		2.5
					M	-20		20
DIGITAL LOGIC INPUT								
Logic High Input Voltage	VAH, VENH			TA = TMIN to TMAX	2.4		V	
Logic Low Input Voltage	VAL, VENL			TA = TMIN to TMAX		0.8	V	
Input Current with Input Voltage High	IAH, IENH	VA = VEN = 2.4V			-0.1	0.1	μA	
Input Current with Input Voltage Low	IAL, IENL	VA = 0 VEN = 0.8V			-0.1	0.1	μA	
SUPPLY								
Power-Supply Range					3	15	V	
Positive Supply Current	I+	VEN = VA = 0, V+; V+ = 5.5V; V- = 0			-1.0	1.0	μA	
Negative Supply Current	I-	VEN = VA = 0V, V+; V+ = 5.5V; V- = 0			-1.0	1.0	μA	
IGND Supply Current	IGND	VEN = V+, 0; VA = 0; V+ = 5.5V; V- = 0		TA = +25°C	-1.0	1.0	μA	
				TA = TMIN to TMAX	-1.0	1.0		

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ELECTRICAL CHARACTERISTICS—Single +5V (continued)

(V+ = 5V ±10%, V- = 0, GND = 0, VAH = VENH = +2.4V, VAL = VENL = +0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP (Note 2)	MAX	UNITS
DYNAMIC						
Transition Time	tTRANS	VNO = 3V		90	245	ns
Break-Before-Make Interval	tOPEN		TA = +25°C	10	40	ns
Enable Turn-On Time	tON(EN)		TA = +25°C	90	200	ns
			TA = TMIN to TMAX		275	
Enable Turn-Off Time	tOFF(EN)		TA = +25°C	50	125	ns
			TA = TMIN to TMAX		200	
Charge Injection (Note 3)	Q	CL = 10nF, VS = 0, RS = 0Ω	TA = +25°C	1.5	5	pC

ELECTRICAL CHARACTERISTICS—Single +3V

(V+ = 3V ±10%, V- = 0, GND = 0, VAH = VENH = +2.4V, VAL = VENL = +0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP (Note 2)	MAX	UNITS
SWITCH						
Analog Signal Range	VANALOG	(Note 3)	V-		V+	V
On-Resistance	RON	INO = 1mA, VCOM = 1.5V, V+ = 3V	TA = +25°C	230	375	Ω
			TA = TMIN to TMAX		425	
DYNAMIC						
Transition Time (Note 3)	tTRANS	Figure 2, VIN = 2.4V, VNO1 = 1.5V, VNO8 = 0	TA = +25°C	230	575	ns
Enable Turn-On Time (Note 3)	tON(EN)	Figure 3, VINH = 2.4V, VINL = 0, VNO1 = 1.5V	TA = +25°C	200	500	ns
Enable Turn-Off Time (Note 3)	tOFF(EN)	Figure 3, VINH = 2.4V, VINL = 0, VNO1 = 1.5V	TA = +25°C	75	400	ns
Charge Injection (Note 3)	Q	CL = 10nF, VS = 0, RS = 0Ω	TA = +25°C	1	5	pC

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

Note 3: Guaranteed by design.

Note 4: $\Delta R_{ON} = R_{ONMAX} - R_{ONMIN}$.

Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges, i.e., VNO = 3V to 0 and 0 to -3V.

Note 6: Leakage parameters are 100% tested at maximum rated hot operating temperature, and guaranteed by correlation at +25°C.

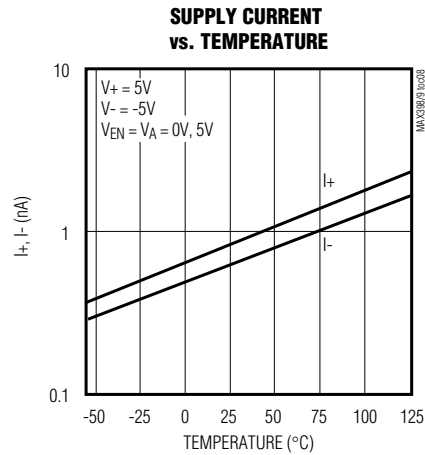
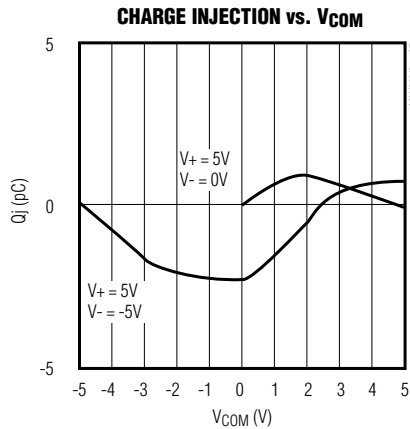
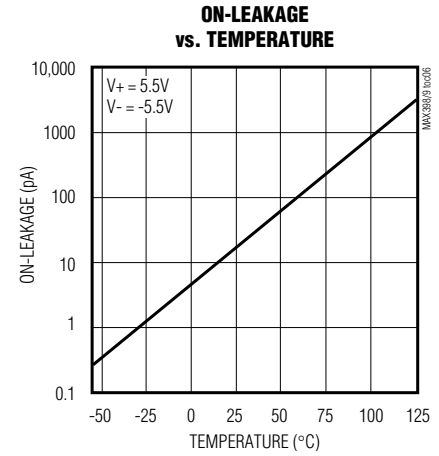
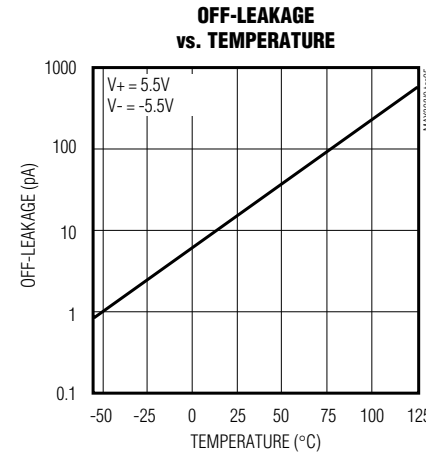
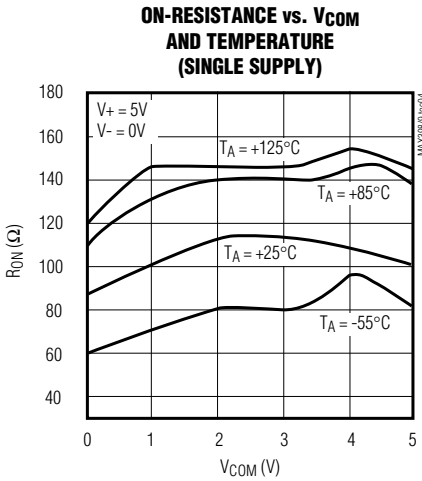
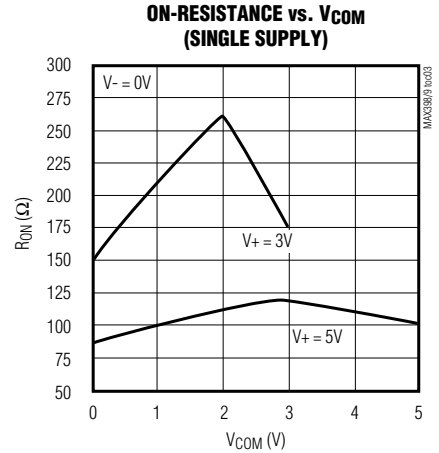
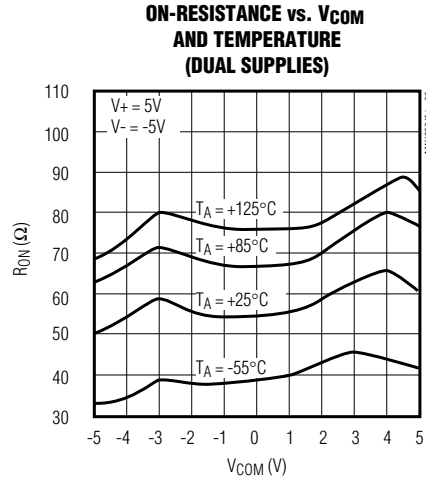
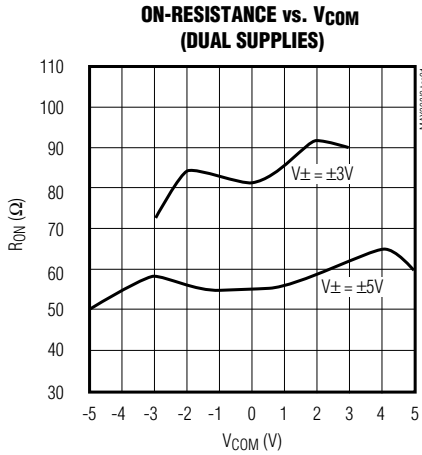
Note 7: Worst-case isolation is on channel 4 because of its proximity to the COM pin. Off-isolation = $20 \log V_{COM} / V_{NO}$. VCOM = output, VNO = input to off switch.

Note 8: Leakage testing at single supply is guaranteed by correlation testing with dual supplies.

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Typical Operating Characteristics

($T_A = +25^\circ\text{C}$, unless otherwise noted.)



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Pin Description

MAX398/MAX399

PIN				NAME	FUNCTION
MAX398		MAX399			
QSOP/DIP/ SO	QFN	QSOP/DIP/ SO	QFN		
1, 15, 16	15, 14, 13	—	—	A0, A2, A1	Address Inputs
—	—	1, 16	15, 14	A0, A1	Address Inputs
2	16	2	16	EN	Enable
3	1	3	1	V-	Negative-Supply Voltage Input
4-7	2-5	—	—	N01-N04	Analog Inputs—Bidirectional
—	—	4-7	2-5	N01A-N04A	Analog Inputs—Bidirectional
8	6	—	—	COM	Analog Output—Bidirectional
—	—	8, 9	6, 7	COMA, COMB	Analog Outputs—Bidirectional
9-12	7-10	—	—	N08-N05	Analog Inputs—Bidirectional
—	—	10-13	8-11	N04B-N01B	Analog Inputs—Bidirectional
13	11	14	12	V+	Positive-Supply Voltage Input
14	12	15	13	GND	Ground

Precision, 8-Channel/Dual 4-Channel, Low-Voltage, CMOS Analog Multiplexers

Applications Information

Operation with Supply Voltages Other than $\pm 5V$

Using supply voltages less than $\pm 5V$ reduces the analog signal range. The MAX398/MAX399 muxes operate with $\pm 3V$ to $\pm 8V$ bipolar supplies or with a $+3V$ to $+15V$ single supply. Connect $V-$ to GND when operating with a single supply. Both device types can also operate with unbalanced supplies, such as $+10V$ and $-5V$. The *Typical Operating Characteristics* graphs show typical on-resistance with $\pm 3V$, $\pm 5V$, $+3V$, and $+5V$ supplies. (Switching times increase by a factor of two or more for operation at $+5V$.)

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence $V+$ on first, then $V-$, followed by the logic inputs, NO, or COM. If power-supply sequencing is not possible, add two small signal diodes ($D1$, $D2$) in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to one diode drop below $V+$ and one diode drop

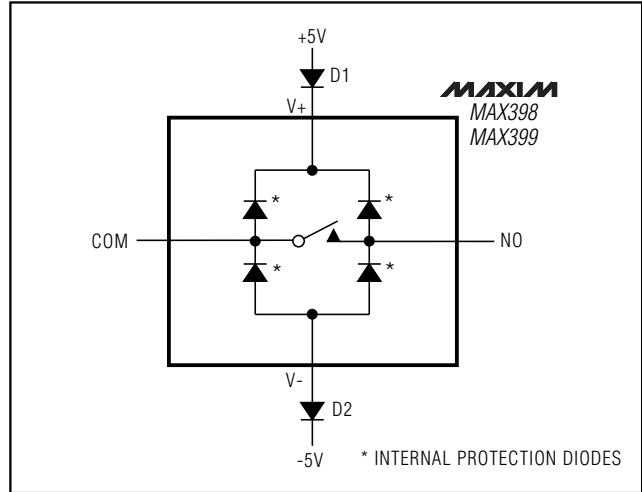


Figure 1. Overvoltage Protection Using External Blocking Diodes

above $V-$, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between $V+$ and $V-$ should not exceed $17V$. These protection diodes are not recommended when using a single supply.

Test Circuits/Timing Diagrams

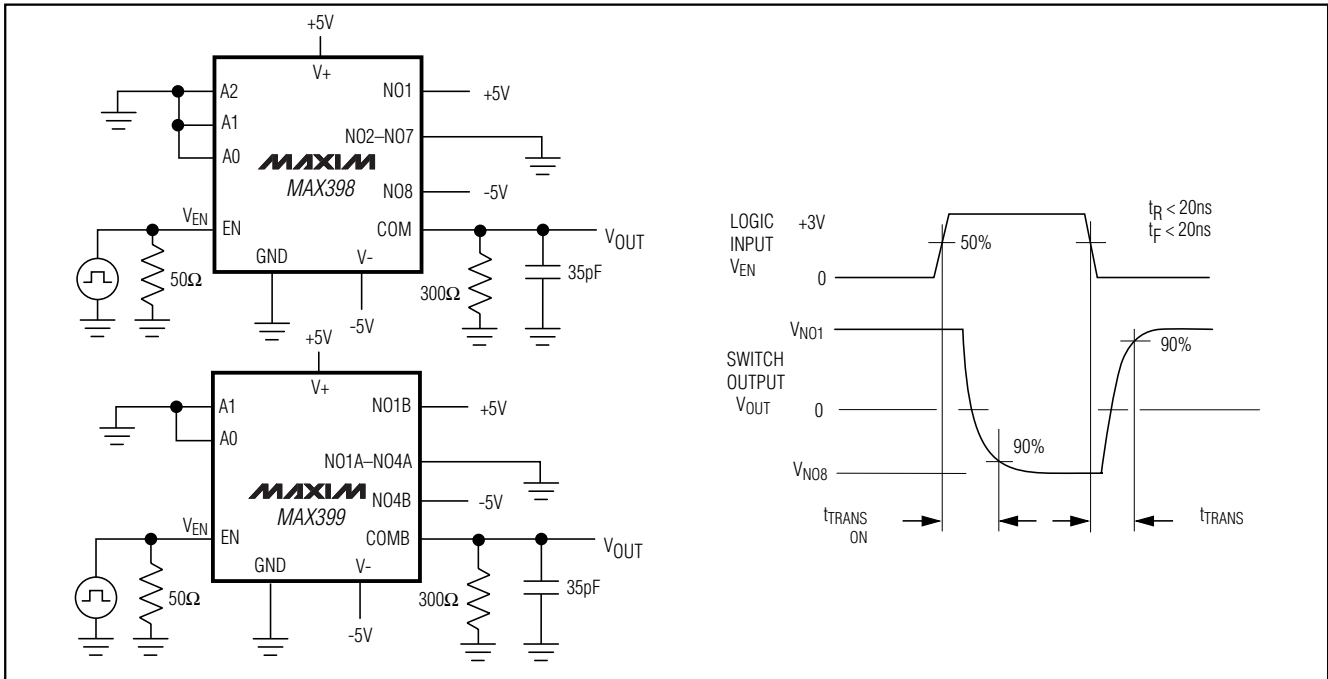


Figure 2. Transition Time

Precision, 8-Channel/Dual 4-Channel, Low-Voltage, CMOS Analog Multiplexers

Test Circuits/Timing Diagrams (continued)

MAX398/MAX399

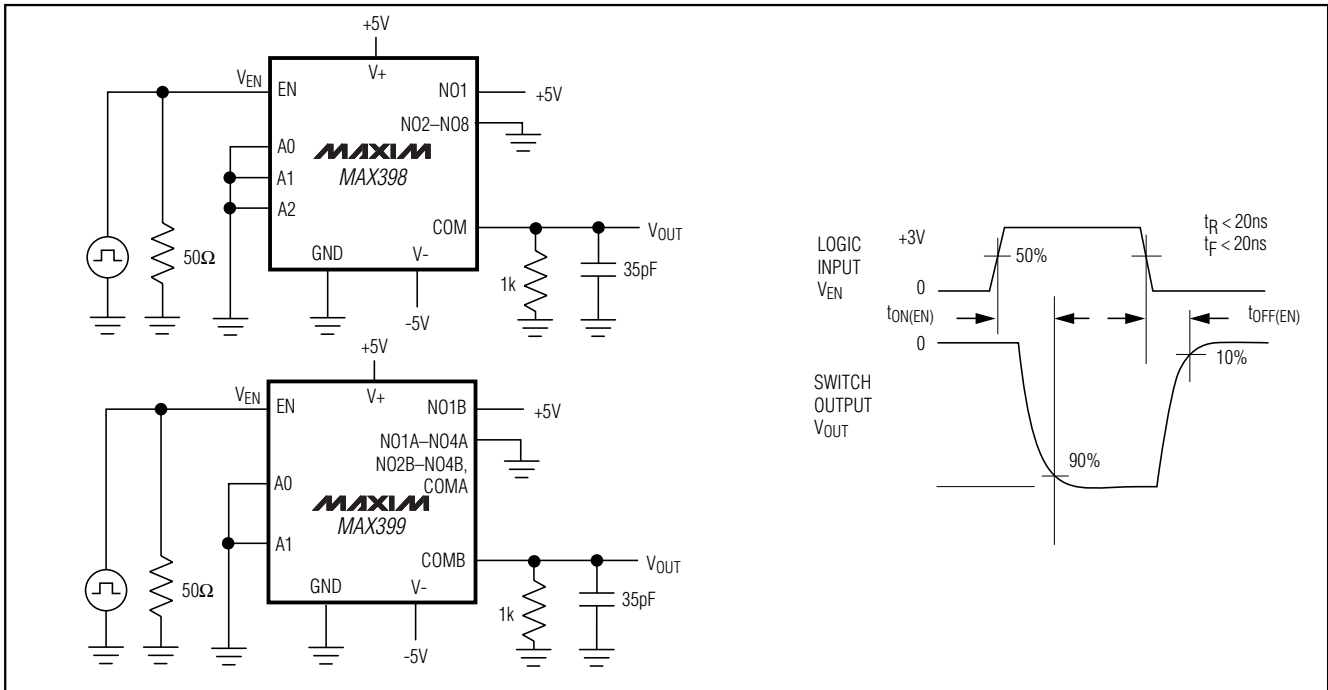


Figure 3. Enable Switching Time

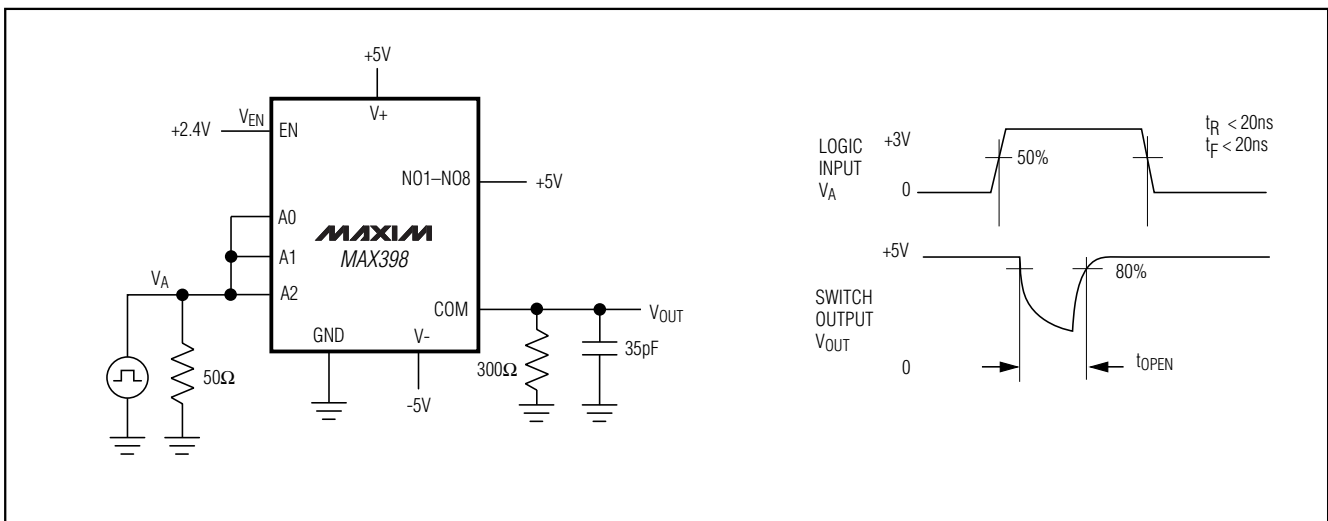


Figure 4. Break-Before-Make Interval

Precision, 8-Channel/Dual 4-Channel, Low-Voltage, CMOS Analog Multiplexers

Test Circuits/Timing Diagrams (continued)

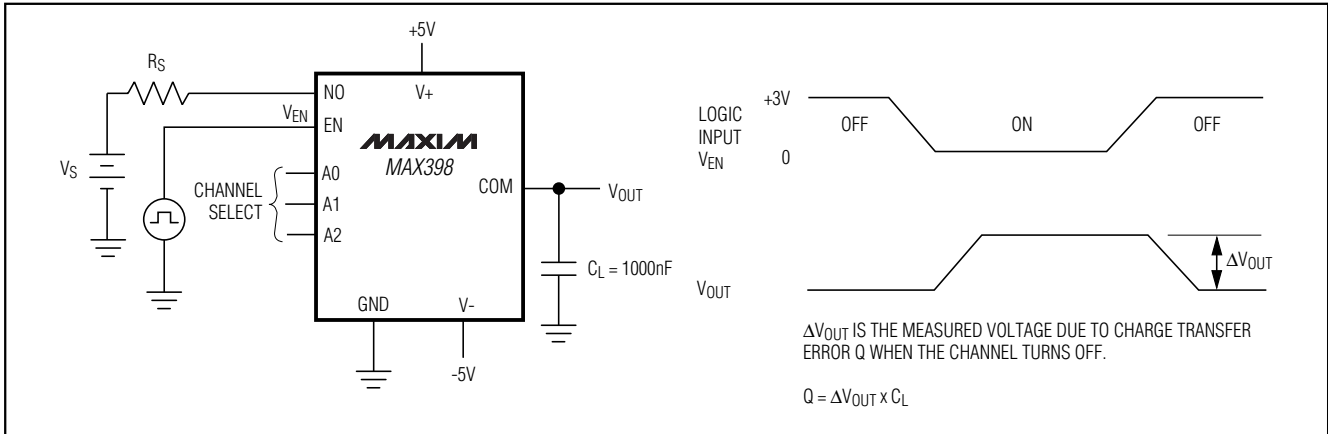


Figure 5. Charge Injection

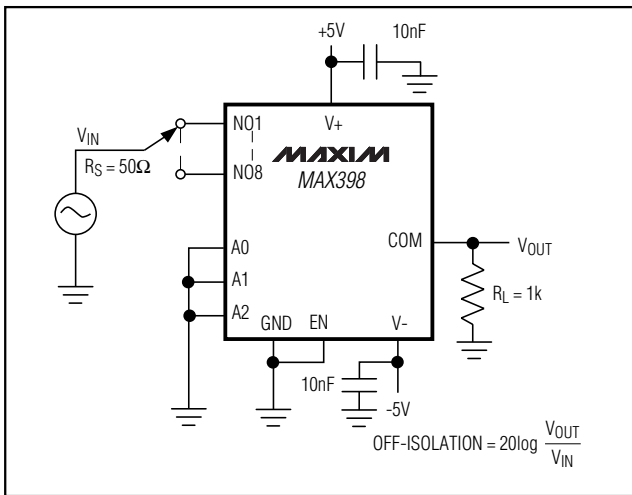


Figure 6. Off-Isolation

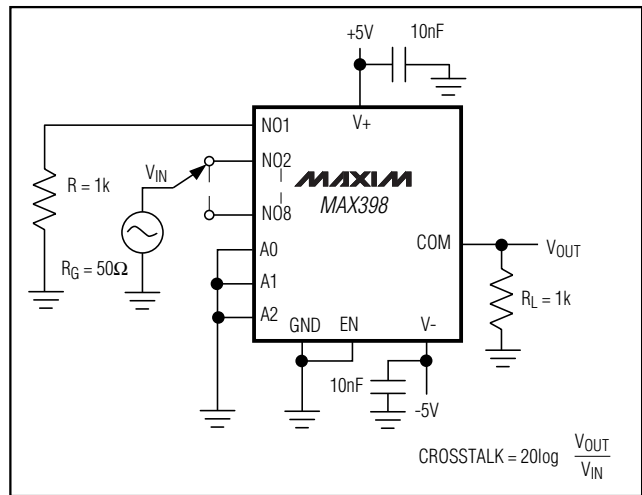


Figure 7. Crosstalk

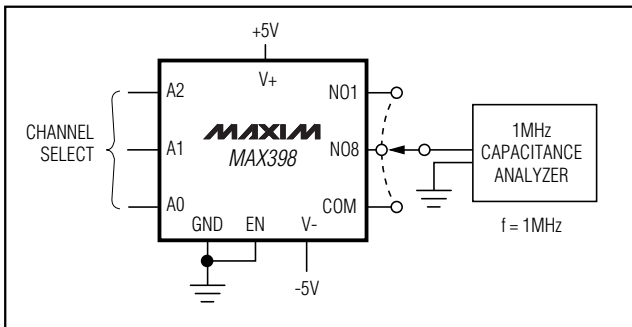


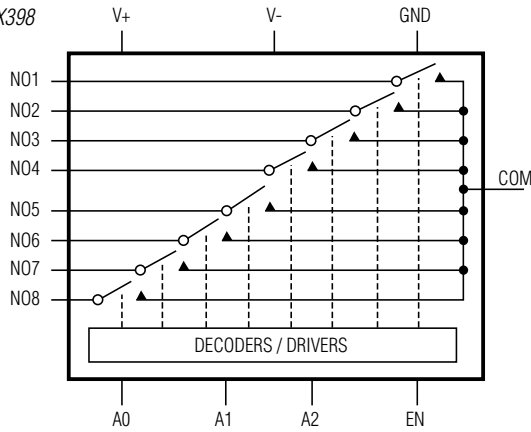
Figure 8. NO/COM Capacitance

Precision, 8-Channel/Dual 4-Channel, Low-Voltage, CMOS Analog Multiplexers

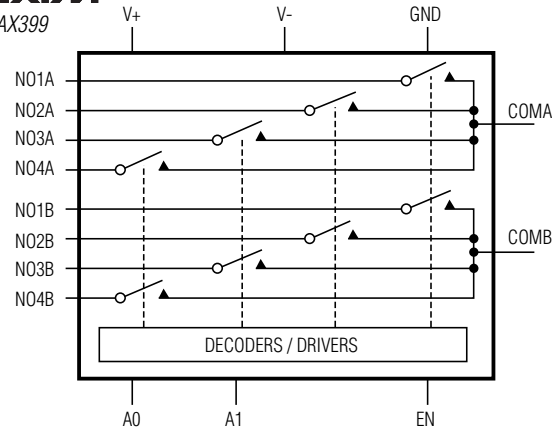
Functional Diagrams/Truth Tables

MAX398/MAX399

MAXIM
MAX398



MAXIM
MAX399



MAX398				
A2	A1	A0	EN	ON SWITCH
X	X	X	0	NONE
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

MAX399			
A1	A0	EN	ON SWITCH
X	X	0	NONE
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

LOGIC "0" $V_{AL} \leq +0.8$ V, LOGIC "1" $V_{AH} \geq +2.4$ V

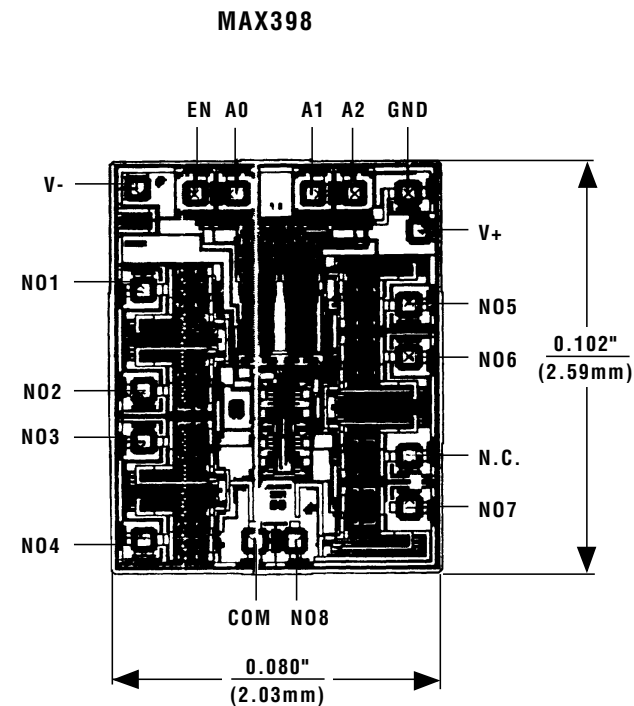
Precision, 8-Channel/Dual 4-Channel, Low-Voltage, CMOS Analog Multiplexers

Ordering Information (continued)

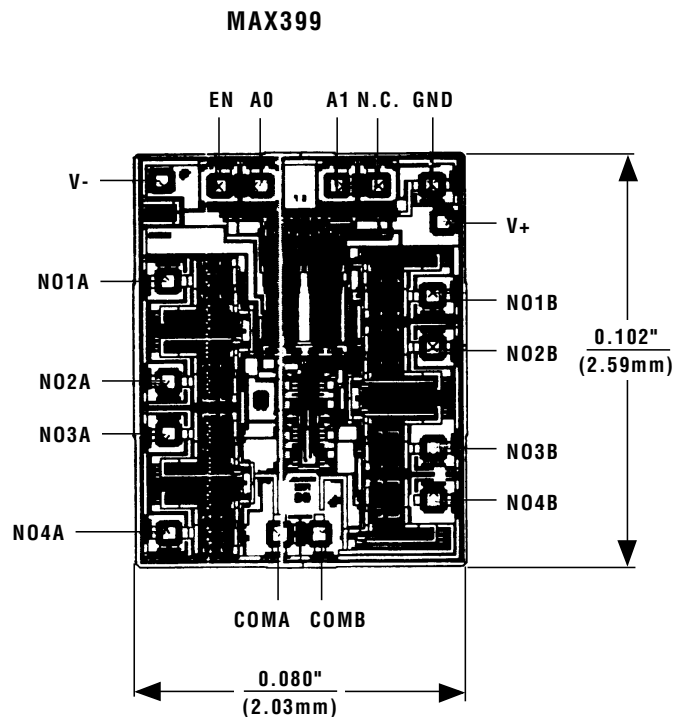
PART	TEMP. RANGE	PIN-PACKAGE
MAX399CGE	0°C to +70°C	16 QFN
MAX399CEE	0°C to +70°C	16 QSOP
MAX399CSE	0°C to +70°C	16 Narrow SO
MAX399CPE	0°C to +70°C	16 Plastic DIP
MAX399C/D	0°C to +70°C	Dice*
MAX399EGE	-40°C to +85°C	16 QFN
MAX399EEE	-40°C to +85°C	16 QSOP
MAX399ESE	-40°C to +85°C	16 Narrow SO
MAX399EPE	-40°C to +85°C	16 Plastic DIP
MAX399EJE	-40°C to +85°C	16 CERDIP**
MAX399MJE	-55°C to +125°C	16 CERDIP**

* Contact factory for dice specifications.
 ** Contact factory for package availability.

Chip Topographies



TRANSISTOR COUNT: 161
 SUBSTRATE CONNECTED TO V+



TRANSISTOR COUNT: 161
 SUBSTRATE CONNECTED TO V+

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